

## Low voltage fast-switching PNP power transistors

### **Features**

- Very low collector-emitter saturation voltage
- High current gain characteristic
- Fast switching speed

## **Applications**

- LED
- Motherboard & hard disk drive
- Mobile equipment
- DC-DC converter

## **Description**

The devices are PNP transistors manufactured using new "PB-HDC" (power bipolar high density current) technology. The resulting transistor shows exceptional high gain performances coupled with very low saturation voltage.

The 2STF2340 complementary PNP is the 2STF1340.

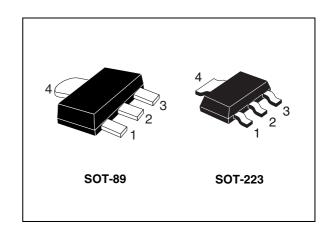


Figure 1. Internal schematic diagram

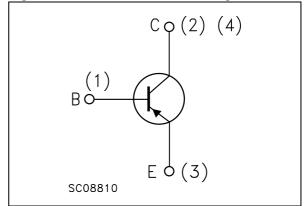


Table 1. Device summary

Order codes	Marking	Packages	Packaging
2STF2340	2340	SOT-89	Tape and reel
2STN2340	N2340	SOT-223	Tape and reel

Electrical ratings 2STF2340, 2STN2340

# 1 Electrical ratings

Table 2. Absolute maximum rating

		Va	lue	
Symbol	Parameter	2STF2340	2STN2340	Unit
		SOT-89	SOT-223	
V <sub>CES</sub>	Collector-emitter voltage (V <sub>BE</sub> = 0)	-4	10	V
V <sub>CEO</sub>	Collector-emitter voltage (I <sub>B</sub> = 0)	nitter voltage (I <sub>B</sub> = 0) -40		V
V <sub>EBO</sub>	Emitter-base voltage (I <sub>C</sub> = 0) -5		V	
I <sub>C</sub>	Collector current -3		Α	
I <sub>CM</sub>	Collector peak current (t <sub>P</sub> < 5 ms) -6		Α	
P <sub>TOT</sub>	Total dissipation at $T_{amb} = 25  ^{\circ}C$ 1.4 1.6		W	
T <sub>STG</sub>	Storage temperature -65 to 150		°C	
T <sub>J</sub>	Max. operating junction temperature 150			°C

Table 3. Thermal data

Symbol	Parameter	SOT-89	SOT-223	Unit
R <sub>thJA</sub> <sup>(1)</sup>	Thermal resistance junction-ambient max	89	78	°C/W

<sup>1.</sup> Device mounted on PCB area of 1 cm<sup>2</sup>

## 2 Electrical characteristics

 $T_{case}$  = 25 °C unless otherwise specified

Table 4. Electrical characteristics

Symbol	Parameter	Test conditions	Min.	Тур.	Max.	Unit
I <sub>CBO</sub>	Collector cut-off current (I <sub>E</sub> = 0)	V <sub>CB</sub> = - 40 V			-0.1	μА
I <sub>EBO</sub>	Emitter cut-off current (I <sub>C</sub> = 0)	V <sub>EB</sub> = - 5 V			-0.1	μΑ
V <sub>(BR)CBO</sub> (1)	Collector-base breakdown voltage (I <sub>E</sub> = 0)	Ι <sub>C</sub> = - 100 μΑ	-40			<b>&gt;</b>
V <sub>(BR)CEO</sub> (1)	Collector-emitter breakdown voltage (I <sub>B</sub> = 0)	I <sub>C</sub> = - 10 mA	-40			٧
V <sub>(BR)EBO</sub>	Emitter-base breakdown voltage ( $I_C = 0$ )	Ι <sub>Ε</sub> = - 100 μΑ	-5			٧
V <sub>CE(sat)</sub> (1)	Collector-emitter saturation voltage	$I_C = -2 A$ $I_B = -100 \text{ mA}$ $I_C = -3 A$ $I_B = -150 \text{ mA}$			-250 -350	mV mV
V <sub>BE(sat)</sub> (1)	Base-emitter saturation voltage	I <sub>C</sub> = - 2 A I <sub>B</sub> = - 100 mA			-1.2	V
h <sub>FE</sub> <sup>(1)</sup>	DC current gain	$\begin{split} I_{C} = -0.1 & A & V_{CE} = -2 & V \\ I_{C} = -1 & A & V_{CE} = -2 & V \\ I_{C} = -3 & A & V_{CE} = -2 & V \end{split}$	100 180	220	450	
f <sub>t</sub>	Transition frequency	$I_C = -0.1 \text{ A}$ $V_{CE} = -5 \text{ V}$ $f = 100 \text{ MHz}$	100			MHz
C <sub>CBO</sub>	Collector-base capacitance (I <sub>E</sub> = 0)	V <sub>CB</sub> = - 10 V		50		pF
t <sub>on</sub> t <sub>off</sub>	Resistive load Turn-on time Turn-off time	$I_{C}$ = - 1.5 A $V_{CC}$ = - 10 V $I_{B(on)}$ = - $I_{B(off)}$ = - 150 mA $V_{BB(off)}$ = 5 V		80 450		ns ns

<sup>1.</sup> Pulse test: pulse duration  $\leq$  300  $\mu$ s, duty cycle  $\leq$  2 %

## 2.1 Electrical characteristics (curves)

Figure 2. Output characteristics

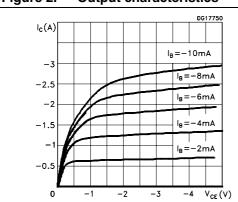


Figure 3. Derating curve

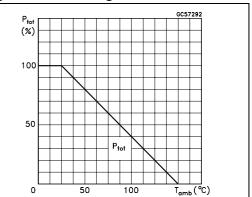
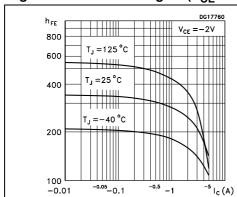


Figure 4. DC current gain ( $V_{CE} = -2 \text{ V}$ ) Figure 5. DC current gain ( $V_{CE} = -5 \text{ V}$ )



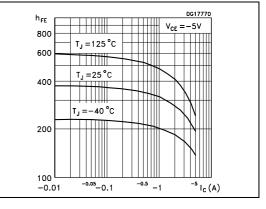


Figure 6. Collector-emitter saturation voltage

-0.05 -0.1

V<sub>CE(sat)</sub> (V) -0.5

-0.1

-0.01

-0.001

-0.01

 voltage
 voltage

 VBE(sof)
 (V)

 TJ = 25°C
 -1

 TJ = 25°C
 -0.8

Figure 7.

-0.4

<sup>-0.05</sup>-0.1

 $V_{BE(sol)}$  (V)  $h_{FE} = 20$   $T_{J} = -40 \,^{\circ}\text{C}$  -0.8 -0.6  $T_{J} = 125 \,^{\circ}\text{C}$ 

**Base-emitter saturation** 

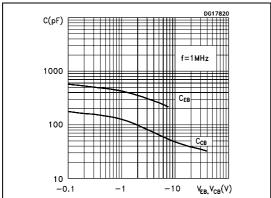
<sup>-5</sup> I<sub>C</sub>(A)

<sup>-5</sup> I<sub>C</sub> (A)

t (n s) V<sub>CC</sub>=-10V V<sub>BE(off)</sub>=5V  $h_{FE} = 10$ 70  $-I_{B(on)} = I_{B(off)}$ 60 50 V<sub>BE(off)</sub>=5V h<sub>FE</sub>=10 1000 40 td -1 B(on) =1 B(off) 30 100 20 t, 0.5 1.5 3 I<sub>c</sub>(A)  $0 \ \ -0.5 \ \ -1 \ \ -1.5 \ -2.0 \ \ -2.5$ Ic (A)

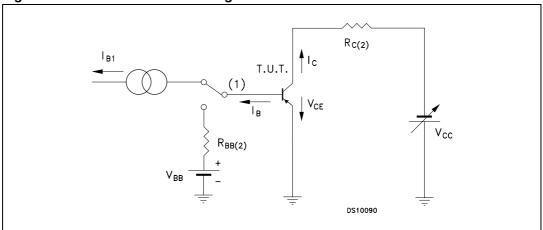
Figure 8. Figure 9. Resistive load switching on Resistive load switching off

Figure 10. **Capacitance curves** 



#### 2.2 **Test circuits**

Figure 11. Resistive load switching test circuit



- 1. Fast electronic switch
- Non-inductive resistor

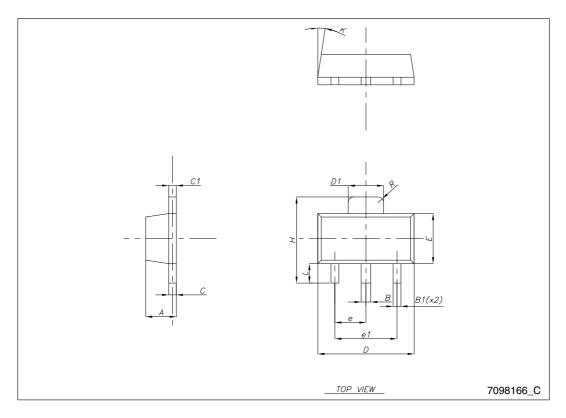
# 3 Package mechanical data

In order to meet environmental requirements, ST offers these devices in different grades of ECOPACK<sup>®</sup> packages, depending on their level of environmental compliance. ECOPACK<sup>®</sup> specifications, grade definitions and product status are available at: <a href="https://www.st.com">www.st.com</a>. ECOPACK<sup>®</sup> is an ST trademark.

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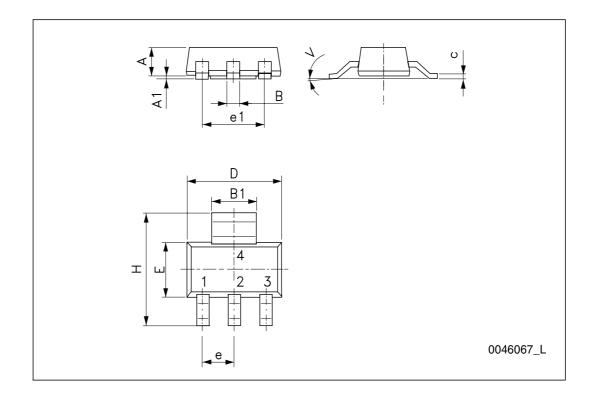
### SOT-89 mechanical data

Dim.	mm			
	Min.	Тур.	Max.	
A	1.40		1.60	
В	0.44		0.56	
B1	0.36		0.48	
С	0.35		0.44	
C1	0.35		0.44	
D	4.40		4.60	
D1	1.62		1.83	
E	2.29		2.60	
е	1.42		1.57	
e1	2.92		3.07	
Н	3.94		4.25	
К	1°		8°	
L	0.89		1.20	
R		0.25		



### SOT-223 mechanical data

DIM.	mm.				
	min.	typ	max.		
Α			1.80		
A1	0.02		0.1		
В	0.60	0.70	0.85		
B1	2.90	3.00	3.15		
С	0.24	0.26	0.35		
D	6.30	6.50	6.70		
е		2.30			
e1		4.60			
E	3.30	3.50	3.70		
Н	6.70	7.00	7.30		
V			10 °		



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2STF2340, 2STN2340 Revision history

# 4 Revision history

Table 5. Document revision history

Date	Revision	Changes	
04-Dec-2007	1	Initial release.	
19-Oct-2009	2	Inserted 2STN2340 in SOT-223 package.	

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